

Orbital-Selective Kondo Entanglement and Antiferromagnetic Order in USb₂

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In heavy-fermion compounds, the dual character of f electrons underlies their rich and often exotic properties like fragile heavy quasiparticles, a variety of magnetic orders and unconventional superconductivity. $5f$ -electron actinide materials provide a rich setting to elucidate the larger and outstanding issue of the competition between magnetic order and Kondo entanglement and, more generally, the interplay among different channels of interactions in correlated electron systems. Here, by using angle-resolved photoemission spectroscopy, we present the detailed electronic structure of USb₂ and observe two different kinds of nearly flat bands in the antiferromagnetic state of USb₂. Polarization-dependent measurements show that these electronic states are derived from $5f$ orbitals with different characters; in addition, further temperature-dependent measurements reveal that one of them is driven by the Kondo correlations between the $5f$ electrons and conduction electrons, while the other reflects the dominant role of the magnetic order. Our results on the low-energy electronic excitations of USb₂ implicate orbital selectivity as an important new ingredient for the competition between Kondo correlations and magnetic order and, by extension, in the rich landscape of quantum phases for strongly correlated f electron systems.

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Heavy fermion systems represent a prototype setting to study the physics of strong correlations, including the variety of quantum phases and their transitions [1,2]. While most attention has been directed to the $4f$ -electron-based rare-earth compounds, the actinide-based compounds also have rich physics but are less studied. Uranium-based materials take a special place in this category. They display intriguing and attractive properties, such as heavy-fermion states, unconventional superconductivity, hidden order, and multiple orders [3–10]. It is generally believed that these properties mainly originate from the interplay between the partially filled shell of $5f$ orbitals and broad bands of conduction electrons. Importantly, $5f$ electrons have an intermediate character between localized $4f$ electrons of rare-earth compounds and itinerant $3d$ electrons of transition metals, and this dual character may be responsible for the wide variety of physical properties of uranium-based materials [3]. The f electrons behave as atomic local moments at high temperature, which interact with the conduction electrons (c - f hybridization) to produce low-energy f -based electronic excitations as the temperature is decreased [11,12]. To elucidate this process, it is important to understand how the dual character of the $5f$ electrons manifests itself in the low-energy electronic structure and physical properties of the uranium-based materials.

Another outstanding issue in the uranium-based compounds is the origin of the magnetic order, especially given

that the $5f$ electrons show dual character. A useful way to address this issue is to study the electronic structure across the magnetic transition by angle-resolved photoemission spectroscopy (ARPES). However, up to now this has only been performed in the ferromagnetic uranium-based compound UTe [13] and antiferromagnetic compound UN [14]. Moreover, a long-standing important issue is whether f electrons are itinerant or localized when the magnetic order occurs. In a class of Ce-based $4f$ -electron materials, there has been considerable evidence that Kondo entanglement is destroyed by the antiferromagnetic order [15,16]. It has also been emphasized that such a Kondo destruction still allows for the onset of hybridization gap [17], as has recently been found in the magnetically ordered phase of CeRhIn₅ [18]. It is timely to address the interplay between Kondo entanglement and magnetic order in $5f$ -electron systems.

Antiferromagnetic USb₂ provides an ideal platform for such studies, as it is a moderately correlated electron system with a quasi-2D electronic structure [19–22]. USb₂ crystallizes in the tetragonal structure of anti-Cu₂Sb type, which orders antiferromagnetically below a high Néel temperature of 203 K [23,24]. Magnetic moments of U ions are aligned ferromagnetically in the (001) planes, which are stacked along the [001] direction in an antiferromagnetic sequence ($\uparrow\downarrow\downarrow\uparrow$) [25]. Previous pioneering ARPES studies on USb₂ have observed a narrow heavy f -electron band below the Fermi level (E_F) and the first kink structure of actinide

materials [26–29]. However, detailed electronic structure evolution across the antiferromagnetic transition is still lacking.

In the present study, we report the Fermi surface topology and band structure of USb_2 by ARPES. Two nearly flat bands can be observed around the Γ and M points at low temperature, which are mainly from the $5f$ electrons. Polarization-dependent measurements reveal that these two nearly flat bands have different orbital character. Temperature-dependent measurements have further shown that the nearly flat band around the Γ point is due to the hybridization between the $5f$ electrons and conduction electrons. A gap opens below the antiferromagnetic transition temperature (203 K) around the M point, which indicates that the other nearly flat band γ around the M point originates from the magnetic order. Our results reveal that Kondo interaction can coexist with the magnetic order by manifesting themselves in different bands and orbitals in the momentum space.

High-quality single crystals of USb_2 were grown from Sb flux method with a starting composition of $\text{U}:\text{Sb} = 1:15$. Data of USb_2 in Figs. 1 and 2 were obtained at the “Dreamline” beam line at the Shanghai Synchrotron Radiation Facility (SSRF) with a Scienta DA30 analyzer, and the vacuum was kept below 5×10^{-11} mbar. The overall energy resolution was 16 meV, and the samples were cleaved *in situ* along the c axis at 20 K. Data in Figs. 3 and 4 were collected by in-house ARPES at 10 K, with the energy resolution of 12 meV and angular resolution of 0.2° .

Electronic structure calculations for USb_2 were performed with a plane-wave basis projected augmented wave method within the density functional theory (DFT) framework, as implemented in the Vienna *ab initio* simulation package (VASP) [33]. All $5f$ electrons of U were treated as Bloch states in the calculations, and the spin-orbit coupling effect was considered using a second variational step. The Perdew-Burke-Ernzerhof (PBE) flavor [34] of the generalized gradient approximation was adopted to describe the exchange-correlation of the valence electrons. Based on the optimized bulk antiferromagnetic unit cell, symmetric (001) slabs with Sb and U terminations were also constructed. The Sb (II)-terminated slab model consists of 10 atomic layers with 15 \AA vacuum layer. An energy cutoff of 600 eV and $21 \times 21 \times 1$ k mesh in the Monkhorst-Pack scheme [35] were employed to converge the structure optimization and static self-consistency calculations to better than 1 meV/atom. For the structure relaxation, only the outer three atomic layers from each surface of the slab were allowed to move until the residual force on every atom is smaller than 0.01 eV/\AA .

Detailed characterization of our USb_2 samples can be found in Fig. S1 in the Supplemental Material [30]. The photoemission intensity map of USb_2 at 20 K taken with 102 eV LH-polarized photons is displayed in Fig. 1(a). The Fermi surface consists of one diamond Fermi pocket

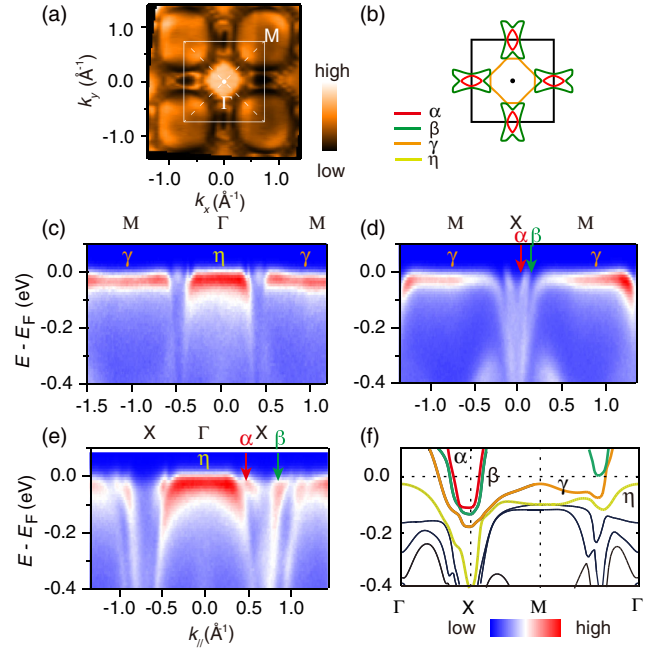


FIG. 1. Fermi surface and band structure of USb_2 taken with 102 eV photons at 20 K with LH-polarized light. (a) Photoemission intensity map of USb_2 at E_F . The intensity is integrated over a window of $(E_F - 20 \text{ meV}, E_F + 20 \text{ meV})$. (b) Calculated Fermi surface of the Sb(II)-terminated surface. Fermi surface contours are drawn with respective colors. (c)–(d) Photoemission intensity distributions along (c) Γ -M, (d) M-X, and (e) Γ -X. (f) Calculated band structure of the Sb(II)-terminated surface. ARPES data with larger energy range can be found in Fig. S2 of the Supplemental Material [30]. Here 102 eV photons are used, and both the f bands and conduction bands can be clearly resolved.

around the zone center, which can be assigned to the γ band. Two Fermi pockets α and β can be observed around the X point. Interestingly, we find large spectral weight around both the Γ and M points, which is due to the formation of heavy quasiparticle bands near E_F . Figures 1(c)–1(e) show the band structure along several high-symmetry directions. Two nearly flat bands called η and γ in the vicinity of E_F can

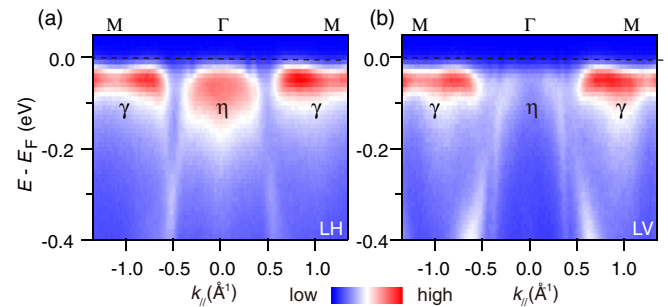


FIG. 2. (a)–(b) Photoemission intensity distributions along Γ -M taken with LH- (a) and LV- (b) polarized light. Curvature plots of the ARPES data can be found in Fig. S4 of the Supplemental Material [30].

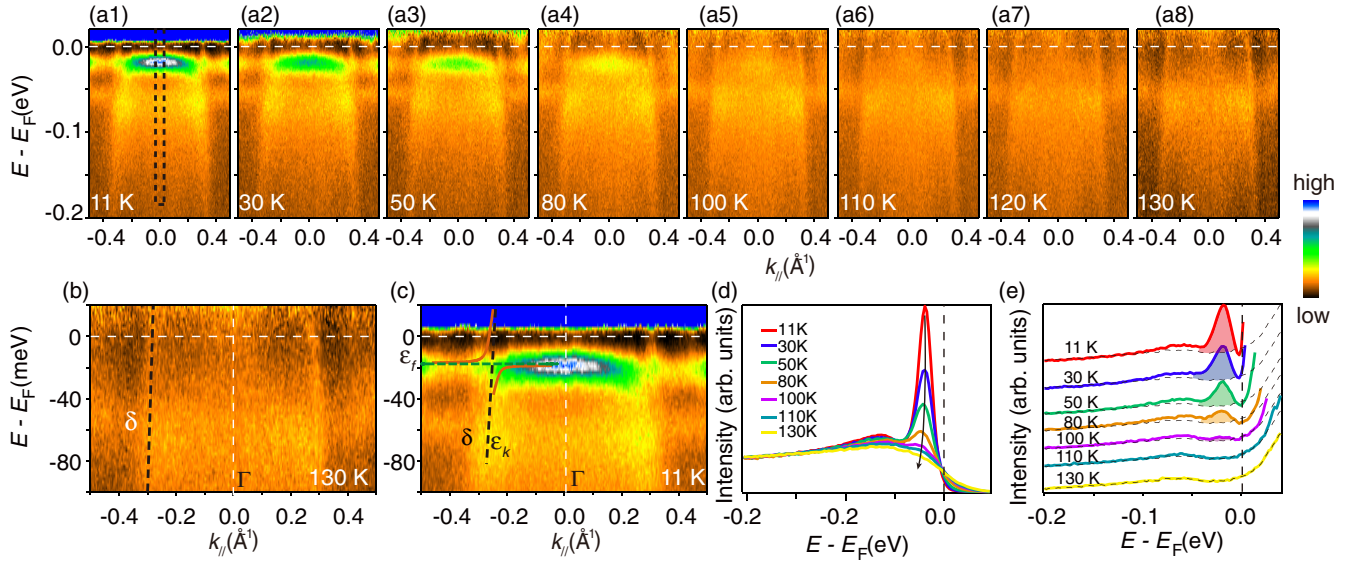


FIG. 3. Temperature evolution of the electronic structure around the Γ point of USb_2 . (a) Photoemission intensity plots along Γ - M at the temperatures indicated. The spectra are divided by the resolution-convoluted Fermi-Dirac distribution. (b)–(c) Zoomed-in ARPES data along Γ - M at 130 (b) and 11 K (c). In panel (c), we present a schematic diagram of the hybridization process under a periodic Anderson model. The black dashed line is the conducting δ band. The orange curve represents the hybridized band. The green line denotes the position of the f band. (d) Temperature dependence of the quasiparticle spectral weight in the vicinity of Γ . Integrated window has been marked by the black dashed block in (a1). (e) Same as (d) after dividing by the Fermi-Dirac function. The dashed line represents the EDC taken at 130 K, and the shaded regions represent the difference between the low temperature data and 130 K data.

be observed around the Γ and M points, respectively. Along Γ - M in Fig. 1(c), only one band γ crosses E_F , which contributes the diamond pocket around the zone center. The η band hybridizes with the nearly flat f band, forming a heavy quasiparticle band near the Γ point. Meanwhile, the nearly flat γ band contributes large spectral weight near E_F around the M point. Detailed electronic structure around the X point can be clearly identified from the band structure along the Γ - X direction in Fig. 1(e), and two conducting

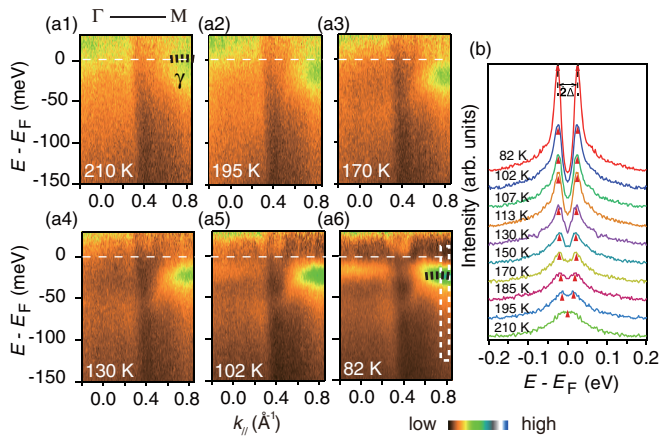


FIG. 4. Antiferromagnetic transition around the M point in USb_2 . (a) Temperature dependence of the band structure along Γ - M . (b) Temperature dependence of the symmetrized EDCs around the M point, and the EDCs are integrated over the white rectangle area in (a6).

bands α and β can be observed crossing E_F , forming two Fermi pockets around the X point. The Fermi energy crossings of these bands can also be clearly observed along M - X , see Fig. 1(d). To identify the cleaved surface for our ARPES measurements, we have performed band structure calculations for both U and Sb terminations and found that our ARPES results agree well with the band structure for the Sb(II)-terminated surface in Figs. 1(b) and 1(f). Detailed identification of the surface terminations can be found in Fig. S3 in the Supplemental Material [30]. Both the Fermi surface and band structure are in good accordance with experimental results: the observed α , β , γ , and η bands near E_F can all be found in the calculation.

The nearly flat η and γ bands around the Γ and M points exhibit weak dispersion near E_F , which are mainly originated from the U $5f$ orbitals. More interestingly, we found that the η band locates at 17 meV below E_F , while the γ band around the M point locates at much higher binding energy of 27 meV. To further identify the orbital character of these bands, we performed photoemission measurements with different polarized photons, which is sensitive to the orbital character of the band structure. Figures 2(a) and 2(b) display the photoemission intensity distributions along the Γ - M direction taken with LH- and LV-polarized light, respectively. For the nearly flat γ band around the M point, the intensity of its spectral weight does not change much with different polarization, while for the η band around the Γ point, f spectral weight near E_F has been greatly reduced with LV-polarized light, comparing with LH polarization.

Because the slit of the analyzer in the SSRF beam line is vertical to the ground. For our ARPES measurements, LV polarization is used to detect the pure even parity orbitals, and LH polarization for odd parity orbitals. Therefore, the η band mainly comes from the odd parity orbitals, while the γ band from orbitals without a pure parity.

In order to reveal the origins of these two nearly flat bands in USb_2 , we performed detailed temperature-dependent measurements with 21.2 eV photons both around the Γ and M points. Figure 3 displays the temperature evolution of the electronic structure around Γ after dividing by the Fermi-Dirac function. While at 130 K in Fig. 3(a), only one conduction band δ with fast dispersion can be observed. Upon decreasing temperature, weakly dispersive f -electron feature gradually emerges with increasing weight near E_F . This temperature dependent evolution can be further illustrated by the energy distribution curves (EDCs) around the Γ point in Fig. 3(d). Figures 3(b) and 3(c) present a detailed comparison of the electronic structure near E_F at 130 and 11 K. At 130 K, only the conducting δ band can be resolved in Fig. 3(b). At 11 K, an obvious f -electron feature near E_F can be clearly observed in Fig. 3(c), which is due to the hybridization between the f band and the conducting δ band. This results in the redistribution of the f spectral weight and forms the weakly dispersive band near E_F . This hybridization process can be described under the periodic Anderson model, as illustrated in Fig. 3(c). The f states develop with decreasing temperature, enhancing the f -electron spectral weight in Fig. 3(c). Such a process starts from a much higher temperature, and to estimate the onset temperature of the formation of this f band more precisely, we plot the EDCs around the Γ point after dividing by the Fermi-Dirac distribution in Fig. 3(e). From our ARPES data, the f band almost disappears at 130 K. Herein, we use the difference between the lower temperature data and 130 K data to determine the onset temperature, and the shaded region in Fig. 3(e) represents this difference. Since the localized-to-itinerant transition of the f electrons is actually a crossover behavior, it is hard to accurately determine the onset temperature. However, difference can be observed at 100 K which gives the onset temperature of 100 ± 20 K. The observed onset behavior in USb_2 is similar to the evolution of the $4f$ -electron behavior in Ce-based compounds [36–39]. This direct visualization of the hybridization between the f bands and the conduction bands signifies the onset of Kondo correlations between the local moments with conduction electrons.

USb_2 orders antiferromagnetically below a high Néel temperature of 203 K [23,24]. To study the evolution of the electronic structure across this phase transition, we performed temperature dependent measurements along Γ - M from 82 up to 210 K and found the γ band around the M point changes dramatically. At 210 K, above the transition temperature, some spectral weight can be observed at E_F , which was enhanced and shifted away from E_F with

lowering temperature, resulting in an energy gap opened at E_F . From the symmetrized EDCs of the γ band around the M point, we can track the gap opening behavior. This gap opens between 195 and 210 K, and the gap size gradually increases with decreasing temperature and saturates at low temperature. The largest gap size is about 27 meV at 80 K. The opening temperature of the gap is in line with the antiferromagnetic transition temperature (203 K) in USb_2 , indicating that the formation of the nearly flat γ band is related to the magnetic order. Detailed temperature dependence of the intensity for the two nearly flat bands can be found in Figs. S5 and S6 in the Supplemental Material [30].

In heavy-fermion compounds, containing $4f$ or $5f$ electrons, the interplay of localization and itinerancy is central to understanding their exotic properties. The f electrons are essentially localized in the paramagnetic state at high temperature. As the temperature is lowered, their exchange coupling to conduction electrons leads to the formation of heavy quasiparticles and become itinerant. The competition between the Kondo effect and RKKY interaction determines the ground state, and is a central issue of the field.

In this work, we observed two nearly flat bands in USb_2 located at the Γ and M points, respectively, which show obviously different behavior with temperature. Polarization-dependent measurements further reveal that they are from different orbitals. Temperature-dependent behavior of the nearly flat band around the Γ point is similar to the localized-to-itinerant crossover of $4f$ electrons in Ce-based compounds [36], which can be assigned to the Kondo interaction of $5f$ states with conduction electrons in USb_2 . While for the γ band around the M point, the opening of a gap around 203 K is consistent with the antiferromagnetic transition temperature of USb_2 . This different temperature-dependent behavior of the two nearly flat bands may arise from two types of orbital selectivity. One is that the conduction electron states near the Γ and M points are different. This situation has been recently reported by Jang *et al.* in the Kondo semimetal CeSb [40]. The other is that the distinction between the Γ and M points reflects the involvement of different $5f$ orbitals. Our results can be explained by the latter of $5f$ -electron orbital selectivity, since the main contribution of these two bands is from the f orbitals, by comparing with the electronic-structure calculations in Fig. S7 in the Supplemental Material [30]. This orbital-selective behavior of $5f$ states manifests itself in different bands in the momentum space, which reconciles the Kondo entanglement with the antiferromagnetic order.

To summarize, our results provide a comprehensive experimental picture of the localized-to-itinerant crossover behavior in actinide compounds, and reveal the electronic structure evolution across the antiferromagnetic transition. More importantly, the results suggest that the orbital selectivity of the $5f$ electrons facilitates the existence of itinerant $5f$ electrons in the antiferromagnetic state of

USb₂. We expect this new insight to be important for obtaining a complete microscopic understanding of the uranium-based materials and, by extension, the multiple-orbital physics of strongly correlated systems in general.

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